**Product data sheet** 

## 1. General description

EEPP<sup>™</sup>- Efficiency Enhanced Pt Planar rectifier in a TO247-2L plastic package.

### 2. Features and benefits

- Fast switching
- Reduces switching losses with improved lower reverse recovery charge
- Soft recovery characteristics
- Low thermal resistance
- Low leakage current
- Planar termination structure
- High operating temperature capability (T<sub>i (max)</sub> = 175°C)
- Higher I<sub>FSM</sub> capability

## 3. Applications

- · Switched-Mode Power Supplies
- Power factor correction diode
- Uninterrupted Power Supply

### 4. Quick reference data

Table 1. Quick reference data

Tubic I. Q	uick reference data						
Symbol	Parameter	Conditions	Values				Unit
Absolute maximum rating							
$V_{RRM}$	repetitive peak reverse voltage			1200			V
I <sub>F(AV)</sub>	average forward current	$δ = 0.5$ ; square-wave pulse; $T_{mb} \le 80$ °C; Fig. 1; Fig. 2; Fig. 3		60			А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 $\mu$ s; $T_{mb} \le 80$ °C; square-wave pulse	120			А	
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	500			А	
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;		550		Α	
Symbol	Parameter	Conditions	Min Typ M		Max	Unit	
Static characteristics							
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 60 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		-	2.8	3.3	V
		I <sub>F</sub> = 60 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>		-	2.2	-	V
Dynamic characteristics							
t <sub>rr</sub>	reverse recovery time $I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A}/\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7			-	55	-	ns
Avalanche energy							
E <sub>AS</sub>	non-repetitive avalanche energy	T <sub>j(init)</sub> = 25 °C		50	-	-	mJ

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	\\\^\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	K — A 001aaa020
2	Α	anode	$\phi$ $\phi$	00 Taaa020
mb	mb	mounting base; connected to cathod	<b>O</b> K  A  TO247-2L	

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package				
	Name	Description	Version		
BYC60W-1200P TO247-2L		Plastic single-ended through-hole package; heatsink mounted;1 mounting hole; 2 leads TO-247	TO247A-2L		

## 7. Marking

#### Table 4. Marking codes

Type number	Marking codes
BYC60W-1200P	BYC60W-1200P

## 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage		1200	V
$V_{RWM}$	crest working reverse voltage		1200	V
$V_R$	reverse voltage	DC	1200	V
I <sub>F(AV)</sub>	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 80$ °C; Fig. 1; Fig. 2; Fig. 3	60	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 80 °C; square-wave pulse	120	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	500	Α
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	550	А
T <sub>stg</sub>	storage temperature		-65 to 175	°C
T <sub>j</sub>	junction temperature		175	°C

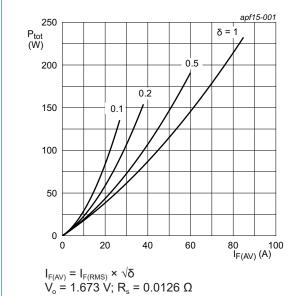
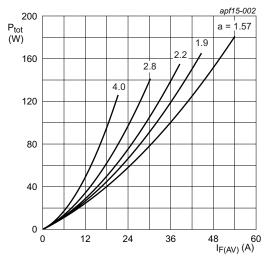


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor =  $I_{F(RMS)}/I_{F(AV)}$ Vo = 1.673 V; Rs = 0.0126  $\Omega$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

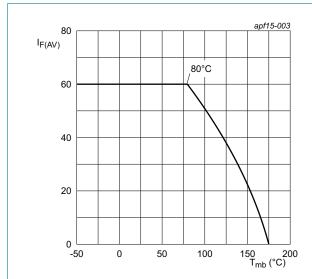


Fig. 3. Forward current as a function of mounting base temperature; maximum values

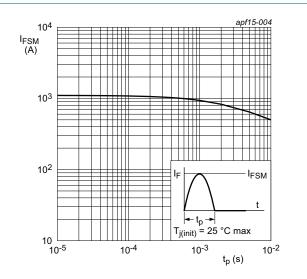
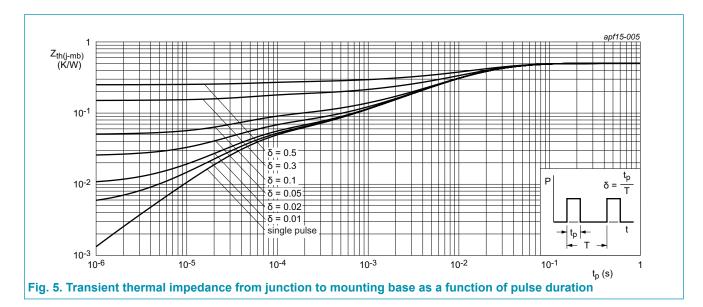


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

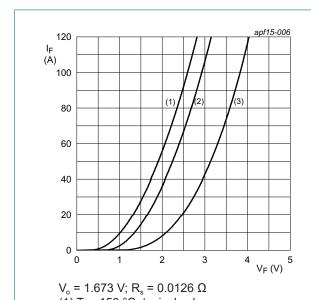
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	Fig. 5	-	-	0.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	45	-	K/W



## 10. Characteristics

### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V <sub>F</sub> forward current		I <sub>F</sub> = 60 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>		2.8	3.3	V
		I <sub>F</sub> = 60 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	2.2	-	V
I <sub>R</sub> reverse current		V <sub>R</sub> = 1200 V; T <sub>j</sub> = 25 °C		-	250	μA
		V <sub>R</sub> = 1200 V; T <sub>j</sub> = 150 °C	-	-	2	mA
Dynamic	characteristics					
Q <sub>r</sub> reverse charge		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	952	-	nC
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$	-	2920	-	nC
	$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 150 \text{ °C}; Fig. 7$	-	3425	-	nC	
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	55	-	ns
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	96	-	ns
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$	-	194	-	ns
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 150 \text{ °C}; Fig. 7$	-	212	-	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	20	-	А
		$I_F = 50 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_i = 125 \text{ °C}; Fig. 7$	-	30.2	-	А
		I <sub>F</sub> = 50 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/μs; T <sub>i</sub> = 150 °C; <u>Fig. 7</u>	-	32.3	-	А
Avalanch	ne energy		J		<u> </u>	
E <sub>AS</sub>	non-repetitive avalanche energy	T <sub>j(init)</sub> = 25 °C	50	-	-	mJ



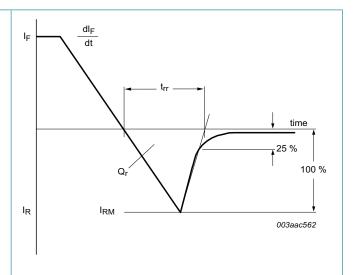
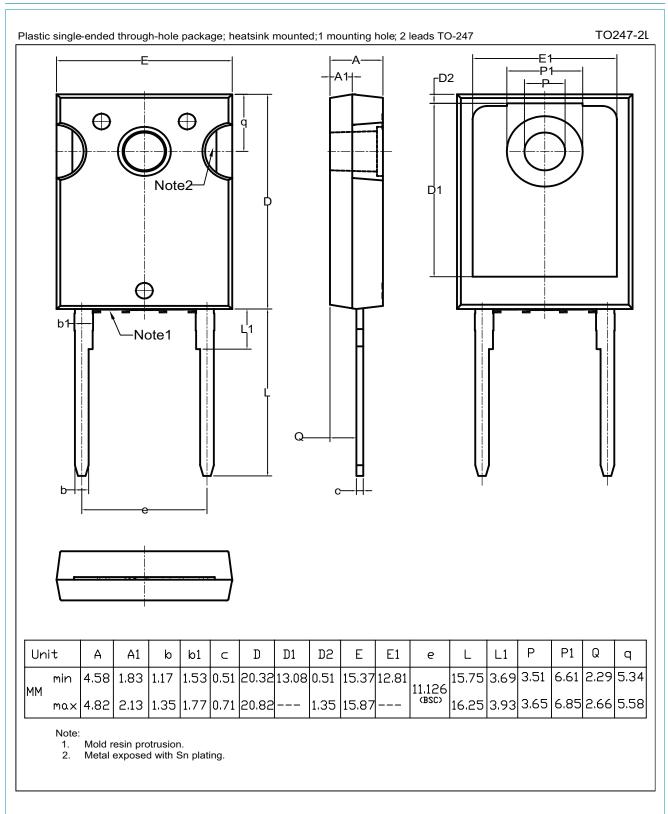


Fig. 7. Reverse recovery definitions; ramp recovery

## 11. Package outline



### 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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